



Bipolar PNP Bare Die – BTP6216

Part Description

The BTP6216 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -40V
- VCEO = -30V
- VEBO = -5V
- hFE = 82-390 @ VCE = -2V, IC = -1A
- VCE(Sat) = -0.33V @ IC = -2A, IB = -100mA
- fT = - MHz @ VCE = - V, IE = - A
- COBO = - pF @ VCB = - V

Features

Low VCE(sat)

Die Size (Unawn)

1050 μ m X 1050 μ m, 41 Mils X 41 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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